

**UNITED STATES
SECURITIES AND EXCHANGE COMMISSION
Washington, D.C. 20549**

FORM 8-K

CURRENT REPORT

Pursuant to Section 13 or 15(d) of the
Securities Exchange Act of 1934

Date of Report (Date of Earliest Event Reported): November 10, 2021

Odyssey Semiconductor Technologies, Inc.

(Exact Name of Registrant as Specified in its Charter)

Delaware (State or other Jurisdiction of Incorporation)	333-234741 (Commission File Number)	84-1766761 (I.R.S. Employer Identification No.)
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**9 Brown Road
Ithaca, NY 14850**
(Address of Principal Executive Offices)

Registrant's telephone number, including area code: **(607) 351-9768**

N/A
(Former Address of Principal Executive Offices)

Check the appropriate box below if the Form 8-K filing is intended to simultaneously satisfy the filing obligation under any of the following provisions (*see* General Instruction A.2. below):

- Written communications pursuant to Rule 425 under the Securities Act (17 CFR 230.425)
- Soliciting material pursuant to Rule 14a-12 under the Exchange Act (17 CFR 240.14a-12)
- Pre-commencement communications pursuant to Rule 14d-2(b) under the Exchange Act (17 CFR 240.14d-2(b))
- Pre-commencement communications pursuant to Rule 13e-4(c) under the Exchange Act (17 CFR 240.13e-4(c))

Indicate by check mark whether the registrant is an emerging growth company as defined in Rule 405 of the Securities Act of 1933 (§230.405 of this chapter) or Rule 12b-2 of the Securities Exchange Act of 1934 (§240.12b-2 of this chapter).

Emerging growth company

If an emerging growth company, indicate by check mark if the registrant has elected not to use the extended transition period for complying with any new or revised financial accounting standards provided pursuant to Section 13(a) of the Exchange Act.

Securities registered pursuant to Section 12(b) of the Act: None.

Section 7 – Regulation FD

Item 7.01. Regulation FD Disclosure

On November 10, 2021, Odyssey Semiconductor Technologies, Inc. (the “Company”) reported its financial results for the quarter ended September 30, 2021. On the same day, the Company is also making available on its website a presentation regarding the financial results.

Copies of the press release and the presentation are furnished hereto as Exhibit 99.1 and Exhibit 99.2, respectively. The information contained in this Current Report on Form 8-K (including the exhibits) is being furnished and shall not be deemed “filed” for the purposes of Section 18 of the Securities Exchange Act of 1934, as amended (the “Exchange Act”), or otherwise subject to the liabilities of that Section, nor shall it be deemed incorporated by reference in any filing under the Securities Act of 1933, as amended, or the Exchange Act, except as otherwise expressly stated in such filing.

Section 9 – Financial Statements and Exhibits

Item 9.01. Financial Statements and Exhibits

(c) Exhibits

Exhibit No.	Description
99.1	Press Release dated November 10, 2021
99.2	Presentation dated November 10, 2021
104	Cover Page Interactive Data File, formatted in Inline XBRL document

SIGNATURES

Pursuant to the requirements of the Securities Exchange Act of 1934, as amended, the Registrant has duly caused this report to be signed on its behalf by the undersigned thereunto duly authorized.

Date: November 10, 2021

Odyssey Semiconductor Technologies, Inc.

By: /s/ Richard Brown
Name: Richard Brown
Title: Interim Chief Executive Officer



Odyssey Semiconductor Technologies Reports Third Quarter Financial Results and Business Highlights

ITHACA, N.Y., November 10, 2021 -- Odyssey Semiconductor Technologies, Inc. (OTCQB: ODII), a semiconductor device company developing innovative high-voltage, vertical power switching components based on proprietary Gallium Nitride ("GaN") processing technology, today reported financial results and business highlights for its third quarter of 2021.

CEO Commentary

"Odyssey is completing the development of its first vertical GaN product. We are on track and continue to focus on providing engineering samples to customers in the fourth quarter of 2021," said Rick Brown, co-founder, interim CEO, CTO, and Board member. "Odyssey has unique technology for the power switching market including high voltage motors, solar panels, and next generation of 800 volt battery packs in electric vehicles. We continue to add to our strong portfolio of IP."

Financial Highlights

Note: All financials referenced in this release are in conformity with U.S. Generally Accepted Accounting Principles ("GAAP") and comparisons in this release are to the same period in the prior year unless otherwise noted.

- Q3 2021 total revenue of \$174,952, entirely foundry service revenues.
- The company has diligently managed its cash resulting in an ending cash balance of \$3.4 million on September 30, 2021.
- The Net cash used in operations year to date in 2021 was \$1.7 million, which is the equivalent of averaging approximately \$185,000 per month during 2021.

Near-Term Milestones

- Continuing to develop high voltage power switching devices with the already demonstrated vertically conducting GaN transistor and p-n diode.
- Provide customers with engineering samples of the first vertical GaN product.
- Initiating qualifications for Joint Electron Device Engineering Council ("JEDEC") standards.

Conference Call and Webcast: Q3 2022 Results

The company will hold a conference call and webcast consisting of prepared remarks by the founder and CEO Rick Brown as well as the Chairman of the Board John Edmunds along with a slide presentation, and a question-and-answer session at 5:00pm ET (2:00pm PT) on Wednesday, November 10, 2021 to review its third quarter 2021 results. Analysts and investors may pose questions for management during the live webcast on November 10, 2021.

Interested persons may access the live conference call by dialing (877) 270-2148 (U.S./Canada callers) or (412) 902-6510 (international callers). It is recommended that participants call or login 10 minutes ahead of the scheduled start time to ensure a proper connection. An audio replay will be available one hour after the live call until midnight on November 24, 2021, by dialing (877) 344-7529, using passcode 10161717.

The live webcast and slide presentation can be accessed on the company's Investor webpage under the Events & Presentations tab at <https://www.odysseysemi.com/investors/ir-calendar>. The webcast will be archived on the website for future viewing.

Upcoming Investor Conference

The company will participate in the Needham 24th Annual Growth Conference on January 10-14, 2022. The company will provide the time of its group presentation when Needham provides it.

Given the company's progress on its product roadmap, commercialization efforts, and overall corporate developments, it anticipates more active ongoing communications with the investment community.

About Odyssey Semiconductor Technologies, Inc.

Odyssey Semiconductor Technologies, Inc. (www.odysseysemi.com), has developed a proprietary technology that will allow for GaN to replace SiC as the leading high-voltage power switching semiconductor material. Based in Ithaca, NY, the Company owns and operates a 10,000 sq. ft. semiconductor wafer manufacturing facility complete with a mix of class 1,000 and class 10,000 clean space as well as tools for advanced semiconductor development and production. Odyssey Semiconductor also offers a world-class semiconductor device development and foundry service.

Forward-Looking Statements

Statements in this press release that are not descriptions of historical facts are forward-looking statements within the meaning of the safe harbor provisions of the Private Securities Litigation Reform Act of 1995. These forward-looking statements include, but are not limited to, statements about our plans, objectives, forecasts, representations and contentions and are not historical facts and typically are identified by use of terms such as "may," "will," "should," "could," "expect," "plan," "forecast," "anticipate," "believe," "estimate," "predict," "potential," "continue" and similar words, although some forward-looking statements are expressed differently. These forward-looking statements are based on management's current expectations and assumptions and are subject to risks and uncertainties. Factors that could cause actual results to differ materially

from those currently anticipated include, without limitation, risks relating to the results of our research and development activities, including uncertainties relating to semiconductor process manufacturing; the early stage of our GaN-based technology presently under development; our ability to protect our intellectual property rights that are valuable to our business, including patent and other intellectual property rights; our ability to successfully market and sell our technologies; the ability to achieve high volume manufacturing and the size and growth of the potential markets for any of our technologies, the rate and degree of market acceptance of any of our technologies and our ability to raise funding to support operations and the continued development and qualification of our technology.

In light of these risks, uncertainties and assumptions, the forward-looking statements regarding future events and circumstances discussed in this press release may not occur, and actual results could differ materially and adversely from those anticipated or implied in the forward-looking statements. You should not rely upon forward-looking statements as predictions of future events. The forward-looking statements included herein speak only as of the date hereof, and we undertake no obligation to update publicly or privately any forward-looking statements for any reason after the date of this release to conform these statements to actual results or to changes in our expectations.

Investor Relations Contacts:

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**ODYSSEY SEMICONDUCTOR TECHNOLOGIES, INC. AND SUBSIDIARIES
 CONSOLIDATED BALANCE SHEETS**

	<u>September 30,</u> <u>2021</u>	<u>December 31,</u> <u>2020</u>
Assets		
Current Assets:		
Cash	\$ 3,409,429	\$ 272,705
Contract assets	—	62,273
Accounts receivable	48,045	10,877
Deferred expenses	4,941	185,084
Prepaid expenses and other current assets	35,261	33,569
Total Current Assets	3,497,676	564,508
Restricted cash	103,188	103,149
Deferred offering costs	—	—
Property and equipment, net	894,967	986,407
Total Assets	\$ 4,495,831	\$ 1,654,064
Liabilities and Stockholders' Equity		
Current Liabilities:		
Accounts payable and accrued expenses	\$ 119,205	\$ 187,046
Loan payable - short term	\$ 77,278	\$ 53,858
Deferred revenue	30,000	260,447
Total Current Liabilities	226,483	501,351
Loans payable - long term	554,853	621,600
Total liabilities	781,336	1,122,951
Commitments and contingencies		
Stockholders' Equity:		
Preferred stock, \$0.0001 par value, 5,000,000 shares authorized; 0 shares issued and outstanding as of September 30, 2021 and December 31, 2020	—	—
Common stock, \$0.0001 par value, 45,000,000 shares authorized, 12,726,911 and 11,429,661 shares issued and outstanding as of September 30, 2021 and December 31, 2020	1,272	1,143
Additional paid-in capital	10,463,804	4,046,370
Accumulated deficit	(6,750,581)	(3,516,400)
Total Stockholders' Equity	3,714,495	531,113
Total Liabilities and Stockholders' Equity	\$ 4,495,831	\$ 1,654,064

**ODYSSEY SEMICONDUCTOR TECHNOLOGIES, INC. AND SUBSIDIARIES
 CONSOLIDATED STATEMENTS OF OPERATIONS**

For The Three Months Ended September 30, 2021

	<u>2021</u>	<u>2020</u>
Revenues	\$ 174,952	\$ 636,070
Cost of Revenues	<u>47,969</u>	<u>495,915</u>
Gross (Loss) Profit	126,983	140,155
Operating Expenses:		
Research and development	454,658	107,323
Selling, general, and administrative	<u>716,765</u>	<u>339,090</u>
Total Operating Expenses	<u>1,171,423</u>	<u>446,413</u>
(Loss) Income From Operations	(1,044,440)	(306,258)
Other Income:		
Forgiveness of PPP loan and other income	25,013	—
Interest expense	<u>(4,560)</u>	<u>-893</u>
Net (Loss) Income	<u>\$ (1,023,987)</u>	<u>\$ (307,151)</u>
Net (Loss) Income Per Share:		
Basic	\$ (0.08)	\$ (0.03)
Diluted	\$ (0.08)	\$ (0.03)
Weighted Average Number of Common Shares Outstanding:		
Basic	12,726,911	11,199,703
Diluted	12,726,911	11,199,703

ODYSSEY SEMICONDUCTOR TECHNOLOGIES, INC. AND SUBSIDIARIES
CONSOLIDATED STATEMENTS OF OPERATIONS

	For The Nine Months Ended September 30	
	<u>2021</u>	<u>2020</u>
Revenues	\$ 693,074	\$ 1,102,071
Cost of Revenues	<u>792,239</u>	<u>1,106,569</u>
Gross (Loss) Profit	<u>(99,165)</u>	<u>(4,498)</u>
Operating Expenses:		
Research and development	1,073,737	430,592
Selling, general, and administrative	<u>2,285,591</u>	<u>869,643</u>
Total Operating Expenses	<u>3,359,328</u>	<u>1,300,235</u>
(Loss) Income From Operations	(3,458,493)	(1,304,733)
Other Income:		
Forgiveness of PPP loan and other income	238,719	1
Interest expense	<u>(14,407)</u>	<u>—</u>
Net (Loss) Income	<u>\$ (3,234,181)</u>	<u>\$ (1,304,732)</u>
Net (Loss) Income Per Share:		
Basic	<u>\$ (0.26)</u>	<u>\$ (0.12)</u>
Diluted	<u>\$ (0.26)</u>	<u>\$ (0.12)</u>
Weighted Average Number of Common Shares Outstanding:		
Basic	<u>12,320,979</u>	<u>11,173,008</u>
Diluted	<u>12,320,979</u>	<u>11,173,008</u>

ODYSSEY SEMICONDUCTOR TECHNOLOGIES, INC. AND SUBSIDIARIES
CONSOLIDATED STATEMENTS OF CASH FLOWS

	For The Nine Months Ended	
	September 30,	
	<u>2021</u>	<u>2020</u>
Cash Flows From Operating Activities:		

Net loss	\$ (3,234,181)	\$ (1,304,732)
Adjustments to reconcile net loss to net cash (used in) provided by operating activities:		
Stock-based compensation	1,750,070	329,274
Forgiveness of PPP loan	(210,680)	75
Depreciation and amortization	124,631	72,736
Changes in operating assets and liabilities:		
Contract assets	62,273	430,732
Accounts receivable	(37,168)	(184,418)
Prepaid expenses and other current assets	(1,693)	55,657
Deferred expenses	180,143	29,547
Accounts payable and accrued expenses	(67,843)	93,636
Deferred revenue	(230,447)	(106,000)
Total Adjustments	<u>1,569,286</u>	<u>721,239</u>
Net Cash (Used In) Operating Activities	<u>(1,664,895)</u>	<u>(583,493)</u>
Cash Flows From Investing Activities:		
Purchases of property and equipment	(32,506)	(610,487)
	<u>—</u>	<u>—</u>
Net Cash Provided By (Used In) Investing Activities	<u>(32,506)</u>	<u>(610,487)</u>
Cash Flows From Financing Activities:		
Proceeds from sale of common stock, net of costs	4,599,055	—
Proceeds from government loans	193,625	684,580
Repayment of government loans	(26,956)	(1,175)
Proceeds from exercise of stock options	68,438	230,624
Payment of deferred offering costs	—	(40,742)
Payment of deferred loan costs	—	(4,560)
Net Cash Provided By Financing Activities	<u>4,834,162</u>	<u>868,727</u>
Net Increase (Decrease) In Cash and Restricted Cash	<u>3,136,761</u>	<u>(325,253)</u>
Cash and Restricted Cash - Beginning Of Period	<u>375,855</u>	<u>798,283</u>
Cash and Restricted Cash - End Of Period	<u>\$ 3,512,616</u>	<u>\$ 473,030</u>
Cash and Restricted Cash Consisted of the Following:		
Cash	\$ 3,409,429	\$ 370,220
Restricted cash	103,188	102,810
	<u>\$ 3,512,617</u>	<u>\$ 473,030</u>
Supplemental Disclosures of Cash Flow Information:		
Cash paid during the year for:		
Interest	\$ —	\$ 100
Income taxes	\$ —	\$ 500
Non-cash investing and financing activities:		
Issuance of warrants to placement agent	<u>—</u>	<u>\$ —</u>

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Investor Presentation

November 10, 2021

“Safe Harbor” Statement

CAUTIONARY STATEMENT REGARDING FORWARD-LOOKING STATEMENTS

The information contained in this presentation includes some statements that are not purely historical and that are “forward-looking statements” within the meaning of the safe harbor provisions of the Private Securities Litigation Reform Act of 1995. Such forward-looking statements include, but are not limited to, statements regarding the Company’s and its management’s expectations, hopes, beliefs, intentions or strategies regarding the future, including the Company’s financial condition and results of operations. In addition, any statements that refer to projections, forecasts or other characterizations of future events or circumstances, including any underlying assumptions, are forward-looking statements. The words “anticipates,” “believes,” “continue,” “could,” “estimates,” “expects,” “intends,” “may,” “might,” “plans,” “possible,” “potential,” “predicts,” “projects,” “seeks,” “should,” “will,” “would” and similar expressions, or the negatives of such terms, may identify forward-looking statements, but the absence of these words does not mean that a statement is not forward-looking. The term “Company” in this presentation includes Odyssey Semiconductor Technologies, Inc. and its wholly-owned JR2J, LLC subsidiary.

The forward-looking statements contained in this presentation are based on the Company’s and its management’s current judgment, expectations and beliefs, but our actual results, events and performance could differ materially from those expressed or implied by the forward-looking statements. There can be no assurance that future developments actually affecting the Company will be those anticipated. These forward-looking statements involve a number of risks, uncertainties (some of which are beyond the Company’s control) or other assumptions that may cause actual results or performance to be materially different from those expressed or implied by these forward-looking statements, including those relating to potential fluctuations in our operating results, our possible dependence on a few large customers for a substantial portion of our revenue, a loss of revenue if contracts with the U.S. Government, defense or other major customers are cancelled or delayed, our ability to implement innovative technologies, our ability to bring new products to market, achievement of design wins over our competitors, the rate of acceptance of our products in the market, the efficient and successful operation of our wafer fabrication and other facilities, our ability to adjust production capacity in a timely fashion in response to changes in demand for our products, variability in manufacturing yields, our ability to successfully integrate our Ithaca wafer fab or other facilities or entities we may acquire, our ability to obtain a Trusted Foundry accreditation for the wafer fab, industry overcapacity, inaccurate product forecasts and corresponding inventory and manufacturing costs, dependence on third parties, our ability to attract and retain skilled personnel and senior management, the dilution that may be caused to our stockholders’ ownership by our future need of substantial additional funding, our ability to protect our intellectual property, claims of intellectual property infringement and other lawsuits, security breaches and other similar disruption compromising our information, and the impact of government or environmental regulations. Should one or more of these risks or uncertainties materialize, or should any of our assumptions prove incorrect, actual results may vary in material respects from those expressed or implied by any of these forward-looking statements. The Company undertakes no obligation to update or revise any forward-looking statements, whether as a result of new information, future events or otherwise, except as may be required under applicable securities laws.

THESE MATERIALS DO NOT CONSTITUTE ANY OFFER TO SELL, OR THE SOLICITATION OF ANY OFFER TO BUY, ANY SECURITIES OF ODYSSEY OR ANY OTHER ENTITY. ANY PRESENTATION TO THE CONTRARY SHOULD BE IGNORED.

“Odyssey Semiconductor™” and the Odyssey Semi logo are trademarks of Odyssey Semiconductor Technologies, Inc.

Key Messages

- **New Disruptive High-Voltage Power Switching Devices with Strong Intellectual Property**
 - Vertical GaN will provide significant benefits over silicon carbide and lateral GaN
 - Odyssey's proprietary vertical GaN-based device technology enables dramatic efficiency increases over competition for applications up to 10 kV
 - Odyssey is focused on proprietary medium and high voltage GaN power switching devices
- **Rapid Growth in High Voltage – Strong Market Demand**
 - TAM: \$2.5B by 2025, 30% CAGR)
- **Seasoned GaN Team & III-V Semiconductor Fab**
- **Near to Medium Term Growth Strategies**
 - Sample product to customers in Q4 2021
 - Build a business in high voltage electric motors
 - Reduce loss in solar power inverters
 - Get established in electric vehicle supply chains
- **Longer Term Growth Strategies**
 - Enable on-the-go charging for electric transportation
- **Emerging from Development Stage**

Odyssey is pioneering vertical GaN development.
GaN will drive replacement of silicon and silicon carbide in high voltage, high performance power applications.

Odyssey Semiconductor (OTCQB: ODII) at a Glance

Company Overview

- Odyssey Semiconductor is a development stage company focused on fabricating vertical GaN power devices based on its proprietary technology
- Our power devices target the following markets:
 - High voltage industrial motors
 - Solar Power Inverters
 - Electric vehicles
 - Other
- Vertical GaN based power devices set to disrupt the SiC power device market based on its ability to:
 - Operate at higher switching speed
 - Provide lower losses
 - Reduce size and weight of power conversion modules

Odyssey Fabrication Facility in Ithaca, NY



- Founded in 2019
- Seasoned team
- Fully outfitted semiconductor fabrication facility
- CY2020 revenue of ~\$1.4M

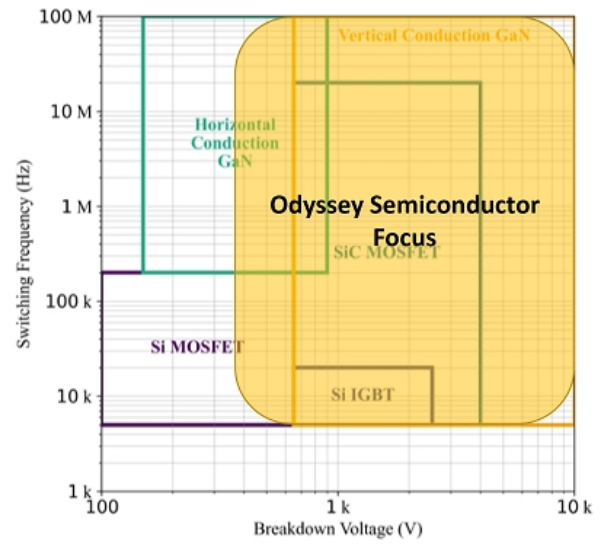
Power Conversion Applications



Odyssey's vertical GaN-based device technology enables dramatic efficiency increases over competition for applications up to 10 kV for industrial motors, electric vehicles, solar power, etc.

Why Focus on Medium and High Voltage GaN Power Electronics?

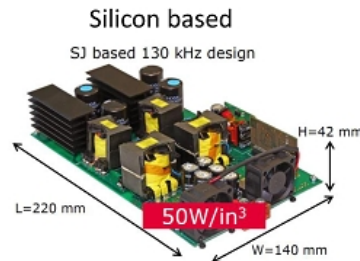
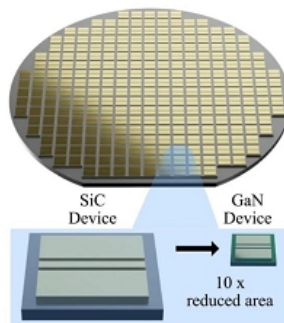
- Silicon - workhorse for over 50 years
- World becoming more power sensitive:
- GaN is a Wide Band Gap Material with better conductivity, more power efficiency and smaller cost footprint for both chip and platform
- GaN embedded on GaN addresses Crystal lattice mismatch with Silicon and proprietary structures and “doping” enable vertical GaN architecture
- Silicon carbide contributes in the range of 600 to 4,000V today
- **Medium to high voltage gallium nitride** will allow significant additional benefits over silicon carbide



Industry experts anticipate medium to high voltage gallium nitride will provide significantly less restrictive and higher power efficiency leading to faster switching at lower costs both for the chip and the surrounding power converter platform than today's silicon carbide solutions.

GaN vs. Si vs. SiC

- GaN is 1000x less resistive than Si and 10x less resistive than SiC
 - 10x more devices per wafer (sq mm) than SiC
 - Simpler process compared to SiC
 - Lowers manufacturing cost
 - Devices can run at higher switching speeds:
 - Reduced size and cost of surrounding components
 - Decreases Power losses – more efficient
 - Can achieve faster switching speed



Source: Infineon

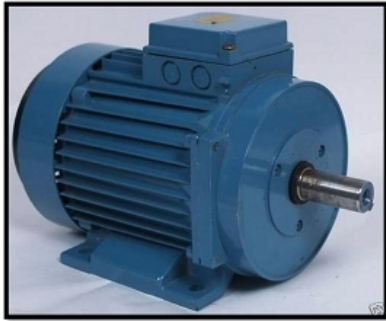
GaN's smaller size fits into smaller form factors and deliver higher power efficiency and lower product costs.

Near to Medium Term Opportunities

Odyssey is focused on three markets: industrial motors, solar power, and electric vehicle recharging

High Voltage Industrial Motors

~45% of world's energy is consumed turning a motor which is a \$100M market today growing at 6% CAGR



Solar Power Inverters

Decrease losses from tying in solar power generation to the electric grid – a \$ 170M+ market today growing at 17% CA



Electric Vehicles

Decrease losses in power converters and power inverters while reducing the size and weight of these modules which is a \$450M mkt today w/CAGR of 38%

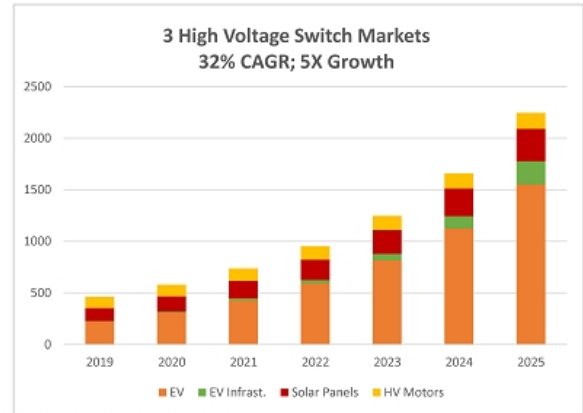
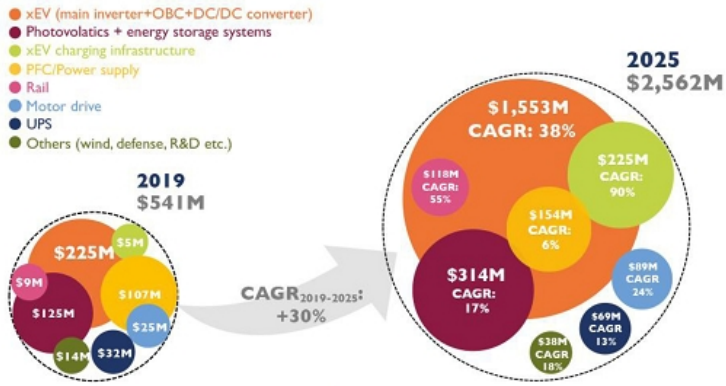


TAM for Odyssey Semiconductor's GaN-based Vertical Conduction Devices

All SiC-based applications addressed by Odyssey' vertical GaN-based conduction devices

2019-2025 power SiC market forecast split by application

(Source: Power SiC: Materials, Devices and Applications 2020, November 2020)



Large growing markets for the technologies that Odyssey will deliver

Source: Yole Development

Expected Timelines for Power Products

2021

- Vertically conducting GaN transistor and p-n diode without regrowth demonstrated
- Continue developing medium to high voltage vertical GaN-based conduction devices
- Provide customers with engineering samples of first vertical GaN product in Q4 – additional time has enabled a better design and an existing product with greater potential range

2022

- Initiate Odyssey qualifications for Joint Electron Device Engineering Council (“JEDEC”) standards
- Ship first vertical GaN-based conduction product to customers for qualification and production
- Provide customers with engineering samples of second generation product

2023

- Expand the production of the first product
- Qualify and begin shipping second product

Financials

- Revenues of \$693,074 year-to-date in 2021
 - Odyssey’s revenue was generated from foundry service business being done for other companies: design, develop, manufacture, and test complex equipment, and provide engineering and technical services. It is not GaN product revenue.
- Diligently managing its cash, the cash balance is \$3.4 million on September 30, 2021
- Cash burn rate is currently averaging \$185,000 per month year-to-date in 2021
 - We believe we can further reduce the burn rate based on foundry contracts already in place to provide process designs services and fab capacity to certain third parties in the coming months. However, at the same time, we will also plan to invest in a few additional resources - so we hope to balance these two activities over the coming quarters

Odyssey Investment Highlights

- **New Disruptive High-Voltage Power Switching Devices with Strong Intellectual Property**
 - Vertical GaN will provide significant benefits over silicon carbide and lateral GaN
 - Odyssey's proprietary vertical GaN-based device technology enables dramatic efficiency increases over competition for applications up to 10 kV
 - Odyssey is focused on proprietary medium and high voltage GaN power switching devices
- **Rapid Growth in High Voltage – Strong Market Demand**
 - TAM: \$2.5B by 2025, 30% CAGR)
- **Seasoned GaN Team & III-V Semiconductor Fab**
- **Near to Medium Term Growth Strategies; Long Growth Runway**

Appendix

Odyssey GaN Processing Technologies Featured in Recent Articles

- *Gearing Up For Next-Gen Power Semis* in Semiconductor Engineering.
- *Going Vertical With GaN Devices* in Semiconductor Engineering.
- *Gallium Nitride Isn't New, But Its Latest Use is of Great Interest in Electric-Car Land* in Motortrend.

Those articles can be accessed on the Odyssey website at <https://www.odysseysemi.com/investors/news-events>